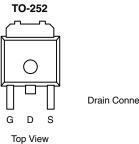


PRODUCT SUMMARY				
V _{DS} (V)	r _{DS(on)} (Ω)	$r_{DS(on)}(\Omega)$ $I_D(A)^a$		
- 80	0.0252 at V _{GS} = - 10 V	- 50	55 nC	
	0.029 at V _{GS} = - 4.5 V	- 47	55110	



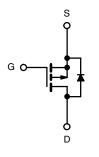
Ordering Information: SUD50P08-25L-E3 (Lead (Pb)-free)

Drain Connected to Tab



• TrenchFET[®] Power MOSFET





P-Channel MOSFET

ABSOLUTE MAXIMUM RATING	S T _A = 25 °C, unle	ess otherwise no	oted		
Parameter		Symbol	Limit	Unit	
Drain-Source Voltage		V _{DS}	- 80	v	
Gate-Source Voltage		V _{GS}	± 20	V	
Continuous Drain Current (T _J = 175 °C)	T _C = 25 °C		- 50 ^a		
	T _C = 70 °C		- 42.5 ^a		
	T _A = 25 °C	I _D	- 12.5 ^{b, c}		
	T _A = 70 °C		- 10.5 ^{b, c}	A	
Pulsed Drain Current		I _{DM}	- 40	A	
Continuous Source-Drain Diode Current	T _C = 25 °C	1	- 50 ^a		
	T _A = 25 °C	I _S	- 6.9 ^{b, c}		
Avalanche Current L = 0.1 mH Single-Pulse Avalanche Energy L = 0.1 mH		I _{AS}	- 45		
		E _{AS}	101	mJ	
Maximum Power Dissipation	T _C = 25 °C		136		
	T _C = 70 °C		95		
	T _A = 25 °C	P _D	8.3 ^{b, c}	— W	
	T _A = 70 °C		5.8 ^{b, c}		
Operating Junction and Storage Temperature Range		T _J , T _{stg}	- 55 to 175	°C	

THERMAL RESISTANCE RATINGS						
Parameter		Symbol	Typical	Maximum	Unit	
Maximum Junction-to-Ambient ^{b, d}	$t \le 10 \text{ sec}$	R _{thJA}	15	18	°C/W	
Maximum Junction-to-Case (Drain)	Steady State	R _{thJC}	0.85	1.1		

c. t = 10 sec. d. Maximum under steady state conditions is 40 $^\circ\text{C/W}.$



Parameter	Symbol	Test Conditions	Min	Тур	Max	Unit	
Static						1	
Drain-Source Breakdown Voltage	V _{DS}	$V_{GS} = 0 V, I_{D} = -250 \mu A$	- 80			V	
V _{DS} Temperature Coefficient	$\Delta V_{DS}/T_{J}$	1 250		- 73		mV/°C	
V _{GS(th)} Temperature Coefficient	$\Delta V_{GS(th)}/T_J$	- I _D = - 250 μΑ		- 5.5			
Gate-Source Threshold Voltage	V _{GS(th)}	$V_{DS} = V_{GS}, I_{D} = -250 \ \mu A$	- 1		- 3	V	
Gate-Source Leakage	I _{GSS}	$V_{DS} = 0 V, V_{GS} = \pm 20 V$			± 100	nA	
Zero Gate Voltage Drain Current	I _{DSS}	$V_{DS} = -80 \text{ V}, V_{GS} = 0 \text{ V}$			- 1		
		V_{DS} = - 80 V, V_{GS} = 0 V, T_{J} = 55 °C			- 10	μΑ	
On-State Drain Current ^a	I _{D(on)}	$V_{DS} \ge 5$ V, $V_{GS} = -10$ V				Α	
Drain-Source On-State Resistance ^a	_	V _{GS} = - 10 V, I _D = - 12.5 A		0.021	0.0252	Ω	
	^r DS(on)	V _{GS} = - 4.5 V, I _D = - 10.5 A		0.024	0.029		
Forward Transconductance ^a	9 _{fs}	V _{DS} = - 15 V, I _D = - 12.5 A		52		S	
Dynamic ^b	•	·			•		
Input Capacitance	C _{iss}			4700		pF	
Output Capacitance	C _{oss}	V_{DS} = - 40 V, V_{GS} = 0 V, f = 1 MHz		320			
Reverse Transfer Capacitance	C _{rss}			235			
Tatal Cata Charge		$V_{DS} = -40$ V, $V_{GS} = -10$ V, $I_D = -12.5$ A		105	160	nC	
Total Gate Charge	Qg			55	85		
Gate-Source Charge	Q _{gs}	V_{DS} = - 40 V, V_{GS} = - 4.5 V, I_{D} = - 12.5 A		16			
Gate-Drain Charge	Q _{gd}			26			
Gate Resistance	Rg	f = 1 MHz		4		Ω	
Turn-On Delay Time	t _{d(on)}			45	70	- ns	
Rise Time	t _r	V_{DD} = - 40 V, R_L = 3.8 Ω		220	330		
Turn-Off Delay Time	t _{d(off)}	$I_{\rm D} \cong$ - 10.5 A, $V_{\rm GEN}$ = - 10 V, $R_{\rm g}$ = 1 Ω		95	145		
Fall Time	t _f			110	165		
Turn-On Delay Time	t _{d(on)}			15	25	- ns	
Rise Time	t _r	V_{DD} = - 40 V, R_L = 3.8 Ω		25	40		
Turn-Off Delay Time	t _{d(off)}	$I_D \cong$ - 10.5 A, V_{GEN} = - 4.5 V, R_g = 1 Ω		105	160		
Fall Time	t _f			100	150		
Drain-Source Body Diode Characteristic	s				-		
Continuous Source-Drain Diode Current	ا _S	T _C = 25 °C			- 50	А	
Pulse Diode Forward Current ^a	I _{SM}				- 40		
Body Diode Voltage	V _{SD}	I _S = - 10.5 A		- 0.8	- 1.2	V	
Body Diode Reverse Recovery Time	t _{rr}			55	85	ns	
Body Diode Reverse Recovery Charge	Q _{rr}	I _F = - 10.5 A, di/dt = 100 A/μs, T _{.1} = 25 °C		110	165	nC	
Reverse Recovery Fall Time	t _a	$F = 10.0 \text{ A}, 0.0 \text{ A} = 100 \text{ A} \mu 0, 10 = 20 \text{ O}$		37		200	
Reverse Recovery Rise Time	t _b] [18		ns	

Notes:

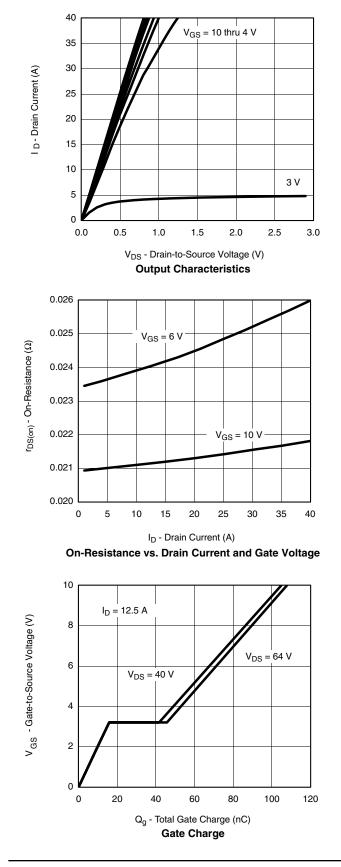
a. Pulse test; pulse width \leq 300 µs, duty cycle \leq 2 %.

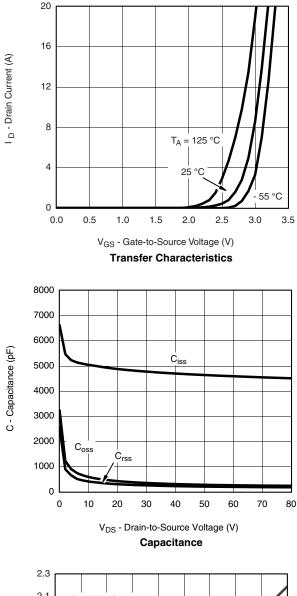
b. Guaranteed by design, not subject to production testing.

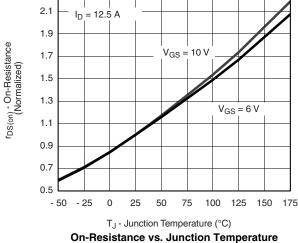
Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.



TYPICAL CHARACTERISTICS 25 °C unless noted



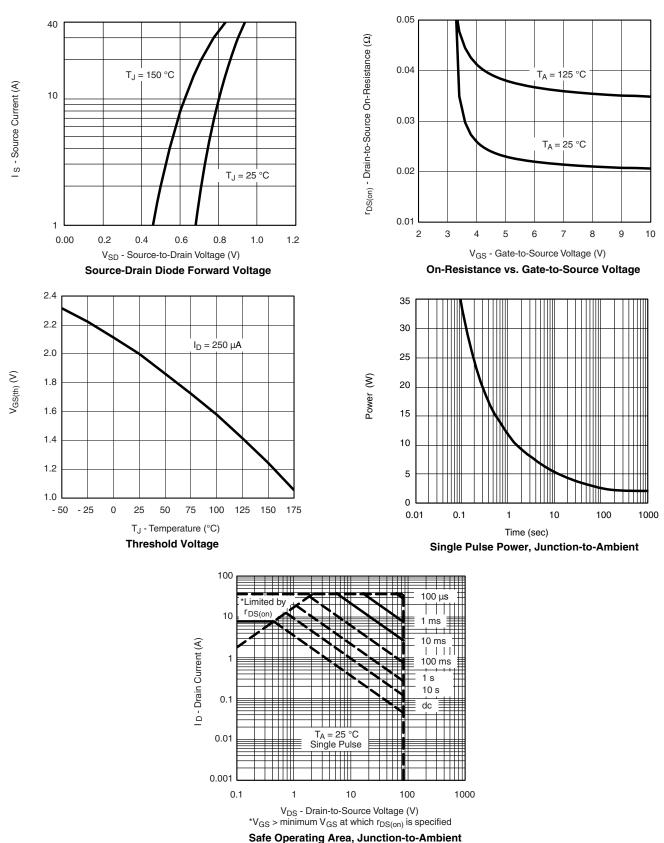




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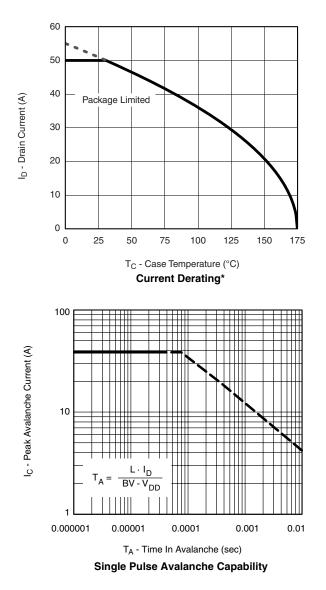


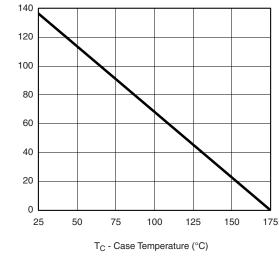
TYPICAL CHARACTERISTICS 25 °C unless noted





TYPICAL CHARACTERISTICS 25 °C unless noted





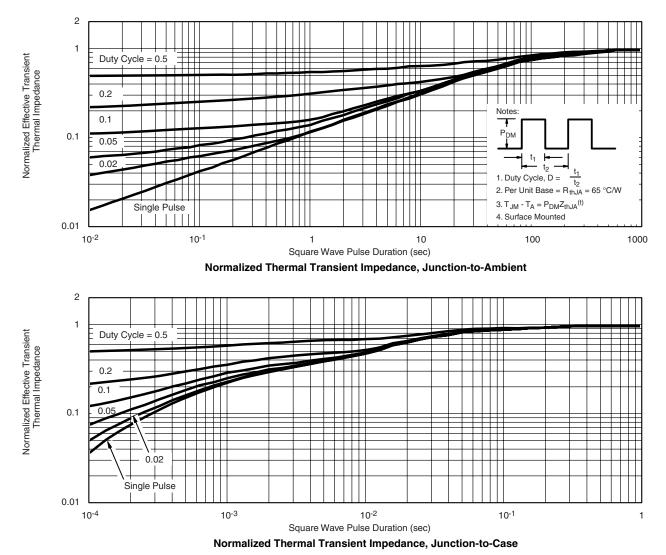
Power

Power Derating

*The power dissipation P_D is based on $T_{J(max)} = 175 \text{ °C}$, using junction-to-case thermal resistance, and is more useful in settling the upper dissipation limit for cases where additional heatsinking is used. It is used to determine the current rating, when this rating falls below the package limit.



TYPICAL CHARACTERISTICS 25 °C unless noted





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